NSN 5962-01-515-0203

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

320.0 milliwatts

Features Provided:

Electrostatic sensitive and programmed

Output Logic Form:

Transistor-transistor logic and complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Cbbl

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital-cmos, logic device, programmable, uv erasable

Voltage Rating And Type Per Characteristic:

5.0 volts power source and 0.8 volts input logic 0 and 2.0 volts input logic 1

Memory Device Type:

Pal

Special Features:

This is an altered 8 macrocell logic array item altered by programming

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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